

# Direct modulation of a hybrid III-V/Si DFB laser with MRR filtering for 22.5-Gb/s error-free dispersion-uncompensated transmission over 2.5-km SSMF

Valentina Cristofori, Francesco da Ros, Yunhong Ding, Alexandre Shen, Antonin Gallet, Dalila Make, Guang-Hua Duan, Leif Katsuo Oxenløwe, Christophe Peucheret

# ▶ To cite this version:

Valentina Cristofori, Francesco da Ros, Yunhong Ding, Alexandre Shen, Antonin Gallet, et al.. Direct modulation of a hybrid III-V/Si DFB laser with MRR filtering for 22.5-Gb/s error-free dispersion-uncompensated transmission over 2.5-km SSMF. ECOC 2016 - 42nd European Conference on Optical Communication, Sep 2016, Dusseldorf, Germany. pp.1142-1144. hal-01464147

HAL Id: hal-01464147

https://hal.science/hal-01464147

Submitted on 2 Sep 2024

**HAL** is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers. L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

# Direct Modulation of a Hybrid III-V/Si DFB Laser with MRR Filtering for 22.5-Gb/s Error-Free Dispersion-Uncompensated Transmission over 2.5-km SSMF

Valentina Cristofori<sup>(1)</sup>, Francesco Da Ros<sup>(1)</sup>, Yunhong Ding<sup>(1)</sup>, Alexandre Shen<sup>(2)</sup>, Antonin Gallet<sup>(2)</sup>, Dalila Make<sup>(2)</sup>, Guang-Hua Duan<sup>(2)</sup>, Leif Katsuo Oxenløwe<sup>(1)</sup>, Christophe Peucheret<sup>(3)</sup>

<sup>(1)</sup> DTU Fotonik, Technical University of Denmark, DK-2800 Kongens Lyngby, Denmark, vari@fotonik.dtu.dk

(2) III-V Lab, a joint lab of Nokia, Thales and CEA, 1 Avenue A. Fresnel, F-91767 Palaiseau, France (3) FOTON Laboratory, CNRS UMR 6082, ENSSAT, University of Rennes 1, F-22305 Lannion, France

**Abstract** Error-free and penalty-free transmission over 2.5 km SSMF of a 22.5 Gb/s data signal from a directly modulated hybrid III-V/Si DFB laser is achieved by enhancing the dispersion tolerance using a silicon micro-ring resonator.

#### Introduction

Directly modulated lasers (DMLs) considered as a promising alternative to external for short-reach applications, including access and data-centre networks, where cost, energy consumption and footprint considerations are of critical importance. Due to the expansion of data traffic, such low cost transceivers are required to operate at higher speed than the currently available 10 Gb/s. These networks will be upgraded soon to operate at 25 Gb/s or more. Even if high-speed DMLs have been demonstrated1-3, they are limited by their low extinction ratio (ER), frequency chirp and reduced dispersion tolerance. In fact, the most challenging issue in the implementation of high-speed directly modulated transceivers is the high susceptibility of 25 Gb/s signals to fiber dispersion at 1550 nm..

To overcome these challenges, managed lasers (CMLs), where the DML is followed by optical filtering, have been introduced<sup>4,5</sup> and successfully demonstrated<sup>6-8</sup>. While these first CML demonstrations made use of discrete filters, a flip-chip implementation of a CML operating at 10.7 Gb/s was demonstrated in [8]. However, this technique requires timeconsuming mechanical alignment and CMLs would clearly benefit from a fully integrated solution that would ease the assembly of the transmitter module and reduce the footprint of the transmitter chip. In this respect, the siliconon-insulator (SOI) platform is promising for the cost-effective implementation of integrated circuits (PICs) and the effectiveness of the use of silicon micro-ring resonators (MRRs) as optical filters for chirp management has already been successfully proved with discrete edge-emitting distributed feedback (DFB) lasers<sup>9,10</sup>. Recently, thanks to the

progress of integration of III-V materials on the SOI platform, a fully integrated III-V/Si hybrid CML has been successfully demonstrated at 10 Gb/s<sup>11</sup>. Furthermore, electronic equalisation and power consuming forward error correction (FEC) circuits should be avoided in short-reach applications since they introduce undesirable latency.

In this work, for the first time to our knowledge, we demonstrate an all-on-silicon transmitter operating at 22.5 Gb/s by directly modulating a III-V/Si hybrid DFB laser followed by a silicon MRR filter. Error-free (BER<10-9) direct detection on-off keying (OOK) signal transmission over 2.5-km of standard single mode fiber (SSMF) is demonstrated without need for dispersion compensation or FEC.

# Laser structure and fabrication

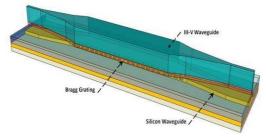
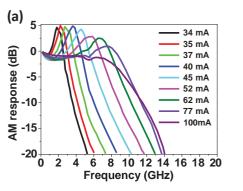


Fig. 1: DFB laser structure.

The hybrid DFB laser was fabricated by wafer-bonding of III-V material on silicon. As shown in Fig. 1, a double taper structure is used to couple efficiently the light between the silicon and III-V waveguides. A Bragg grating with a period  $\Lambda=240$  nm is etched into the silicon waveguide under the III-V waveguide. The laser provides single mode operation with side mode suppression ratio of more than 40 dB. The fabricated DFB laser was soldered on a submount and a bias current threshold of



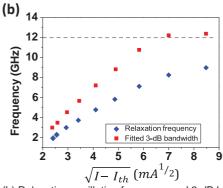


Fig. 2: (a) Measured small signal amplitude responses. (b) Relaxation oscillation frequency and 3-dB bandwidth obtained by fitting the AM response data.

28.5 mA was measured. The small signal amplitude modulation (AM) responses of the DFB laser have been measured for different bias currents from 34 mA to 100 mA and are shown in Fig. 2(a). From these  $S_{21}$  curves, the relaxation oscillation frequencies and the 3-dB bandwidths of the DML have been extracted and plotted versus the square root of the difference between the bias current and the threshold current (Fig. 2(b)). The modulation bandwidth exceeds 12 GHz for bias currents above 100 mA.

### MRR structure and fabrication

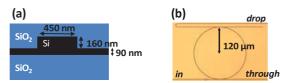
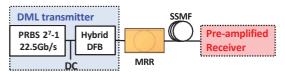


Fig. 3: (a) MRR structure and (b) MRR microscope picture.

The MRR was fabricated on an SOI wafer with a top silicon thickness of 250 nm and a 3-µm buried silicon dioxide layer. Electron-beam (EB) lithography and inductively coupled plasma reactive ion etching were used to define the micro-ring structure shown in Fig. 3(a). Plasmaenhanced chemical vapor deposition (PECVD) was then used to deposit a silica cladding top layer. The rib waveguide has a depth of 160 nm and its width is 450 nm. A microscope picture of the device is shown in Fig. 3(b). Grating couplers are implemented at the in, through and drop ports to couple light in and out of the MRR and the in-to-through total insertion loss of the MRR away from resonance is 9 dB. The diameter of the MRR is 120 µm, which corresponds to a free-spectral range (FSR) of

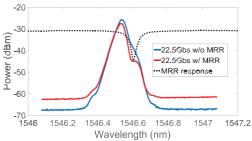


**Fig. 4:** Experimental setup: DML transmitter, MRR filter for ER and dispersion enhancement, transmission fiber (removed for B2B measurements) and pre-amplified receiver.

100 GHz. This parameter was designed in view of future deployment in combination with laser arrays for WDM applications. The measured Q-factor is  $3.8\times10^4$ .

# **Experimental setup**

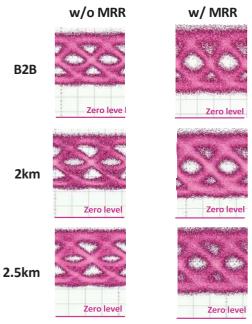
The setup is shown in Fig. 4. The hybrid III-V/Si DFB laser was biased at 130 mA, corresponding to a 3-dB bandwidth of approximately 12 GHz, and directly modulated at 22.5 Gb/s with a 27-1 non-return-to-zero (NRZ) pseudo-random binary sequence (PRBS) signal generated by a bit pattern generator with a peak-to-peak voltage of 3 V. The optical signal at 1546.5 nm was then filtered by the MRR for ER and dispersion tolerance enhancement. The MRR was mounted on a thermal control stage for thermal tuning of the resonance allowing the suppression of part of the low-frequency content of the optical signal spectrum, as shown in Fig. 5. After MRR offset filtering, the signal was transmitted over SSMF and received with a standard pre-amplified receiver followed by an error analyser for biterror-ratio (BER) measurements and a sampling oscilloscope for eye diagram recording. The transmission performance was compared based on BER measurements for 0-, 2- and 2.5-km SSMF without and with the MRR filter.



**Fig. 5:** Signal spectra at 22.5 Gb/s with and without the MRR filter. The MRR transfer function is also shown.

## **Experimental results**

The eye diagrams are shown in Fig. 6 for back-to-back, 2-km and 2.5-km SSMF transmission. They are all measured for a received power of -15 dBm. The back-to-back (B2B) eye



**Fig. 6:** Eye diagrams (10.5 mV/div) at 22.5 Gb/s with and without MRR filter for B2B, 2-km and 2.5-km SSMF.

diagrams show an ER increase from 2 dB (without MRR) to 3 dB (with MRR). After transmission, however, the eye diagrams of the filtered signals are clearly less distorted compared to the unfiltered ones, showing the enhanced dispersion tolerance of the transmitter with the MRR filter. This behaviour is confirmed by the BER performance reported in Fig. 7. The B2B receiver sensitivity (BER= 10<sup>-9</sup>) is improved by more than 3 dB thanks to the MRR filtering. After transmission over SSMF, the accumulated dispersion degrades the quality of the received signal with the DML signal showing an error floor at BER=10<sup>-4</sup>. FEC would thus be required at the receiver, thereby increasing latency and energy consumption. By using the MRR filter, error-free performance can be achieved up to 2.5 km with around 4 dB of power penalty compared to the back-to-back filtered DML, which however corresponds to no penalty when compared with the unfiltered DML back-to-back.

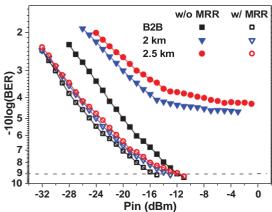


Fig. 7: BER at 22.5 Gb/s with and without MRR filter for B2B, 2-km and 2.5-km SSMF.

#### Conclusions

A hybrid 22.5-Gb/s III-V/SOI filtered DFB DML operating at 1546.5 nm was demonstrated, showing an enhanced dispersion tolerance. Error-free transmission over 2.5-km SSMF was achieved without the use of electronic equalisation techniques, FEC or dispersion compensation, showing no penalty with respect to the DML B2B performance.

# **Acknowledgements**

This research was funded by the European Commission's Seventh Framework Program under grant agreement No. 619626 SEQUOIA.

#### References

- [1] N. Nakahara *et al.*, "Direct modulation at 56 and 50 Gb/s of 1.3 μm InGaAlAs ridge-shaped-BH DFB laser," IEEE Photon. Technol. Lett., Vol. 27, no. 5, p. 534 (2015).
- [2] S. M. R. Montaghiannezam et al., "Single chip 52 Gb/s PAM4 transmission through -58 and +10 ps/nm chromatic dispersion using directly modulated laser" Proc. OFC, Th2A.59, Anaheim (2016).
- [3] A. Abbasi et al., "28 Gb/s direct modulation heterogeneously integrated C-band InP/SOI DFB laser" Proc. OFC, WeA3, Anaheim (2015).
- [4] D. Mahgerefteh et al., "Error-free 250 km transmission in standard fibre using compact 10 Gbit/s chirp-managed directly modulated lasers (CML) at 1550 nm", Electron. Lett., Vol. 41, no. 9, p. 543 (2005).
- [5] D. Mahgerefteh et al., "Chirp managed laser and applications", IEEE J. Sel. Topics. Quantum Electron., Vol. 16, no. 5, p. 1126 (2010).
- [6] S. Chandrasekhar et al., "Flexible transport at 10-Gb/s from 0 to 675 km (11,500 ps/nm) using a chirp-managed laser, no DCF, and a dynamically adjustable dispersioncompensation module", Proc. OFC, PDP30, Anaheim (2005).
- [7] J. Yu et al., "Applications of 40-Gbit/s chirp-managed laser in access and metro networks", J. Lightwave Technol., Vol. 27, no.3, p. 253 (2005).
- [8] Y. Yokoyama et al., "10.709-Gb/s-300-km transmission of PLC-based chirp-managed laser packaged in pluggable transceiver without any optical or electrical dispersion compensation", Proc. ECOC, We.1.c.4, Brussels (2008).
- [9] Y. An et al., "Transmission property of directly modulated signals enhanced by a micro-ring resonator", Proc. OECC, 6F3-3, Busan (2013).
- [10] Q. Zhang et al., "Compact silicon-based DML transmitter with extinction ratio improved for 40G TWDM PON OLT scenarios", Proc. OFC, Tu3E.7, Los Angeles (2015).
- [11] A. Shen et al., "50km error free transmission of fully integrated chirp-managed 10Gb/s directly modulated Cband tunable III-V SOI hybrid lasers", Proc. OFC, M2C.5, Anaheim (2016).